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Design and Analysis of Miniaturized Low Profile and Second-Order Multi-Band Polarization Selective Surface for Multipath Communication Application

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ABSTRACT In this paper, a novel frequency selective surface (FSS) is designed; it has the characteristics of the low profile, second-order, multi-band, and the remarkable polarization selection properties. In the following, such an FSS having polarization selection characteristics will be referred to simply as a polarization selection surface (PSS). In a specific frequency band, the proposed PSS has a second-order selective transmission characteristic for TE and TM waves. Based on the coupling resonance filtering mechanism, the proposed PSS is composed of three metallic layers separated by two layers of dielectric substrates, which serves as the spatial form of the second-order microwave filter. The proposed PSS uses a sub-wavelength periodic structure array consisting of a non-resonant unit, and the unit size and the period within the range of $0.08\lambda_1-0.15\lambda_1$, where the $\lambda_1 = 40.76$ mm is the first passband wavelength of free space, so the PSS miniaturization characteristic is remarkable. The theoretical analysis and measure results show that the proposed bandpass PSS has good second-order polarization selection characteristics, out-of-band suppression level, and the flat transmission band, compared with the first-order bandpass PSS. In the range of incident angle of $0^\circ-60^\circ$, it has a stable frequency response. It provides a reference for the design of a polarization wave generator and a polarization separation structure in a multipath communication system.

INDEX TERMS Angle stability, frequency selective surface, polarization selective, second-order, multi-band.

I. INTRODUCTION

Frequency selective surface (FSS) is a spatial microwave filter. It shows obvious filtering characteristics, can make the electromagnetic wave totally reflect or transmit at the resonance frequency [1]–[4].

At present, FSS has been widely used in the research and design of stealth antenna radome [5], composite absorbing materials [6]–[7], polarization mode converters [8], composite multi-frequency antenna design [9] and multipath communication system [10]. As we all know, modern communication satellite system is a typical multipath communication system, which can serve users in multiple bands at the same time. In the system, FSS is used as a sub-reflector

of the communication antenna, enabling multiple pairs of feeds to work at the same time. For example, it can realize dual-frequency or multi-frequency sharing functions such as X/Ku, S/X or S/X/Ku/Ka bands [11]. Also, it has selective effect on electromagnetic wave polarization mode in its operating frequency. However, there are little researches on FSS polarization selection characteristics [12], [13]. In practical application, in order to weaken the influence of complex electromagnetic environment, resist active jamming, suppress environmental clutter and improve its detection ability. Polarization wave generators or polarization separation structures are needed in satellite communication systems to generate single-mode polarization waves or separate different

polarization modes, so as to load communication information by using single-mode polarization waves in different wavebands. Therefore, the study of FSS with polarization selection characteristics is of great significance for the design of polarization wave generator or polarization separation structure [14]. The working principle of polarization selective antenna in communication satellite system is shown in Fig.1.

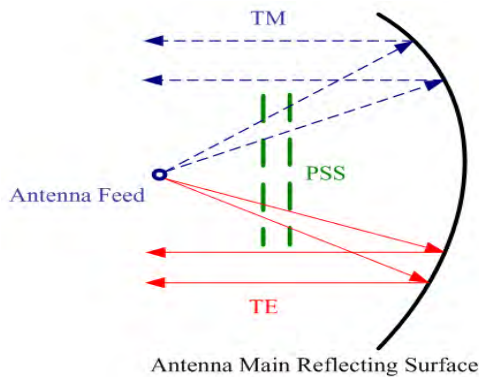


FIGURE 1. The working principle of polarization selective antenna.

In Fig.1, the antenna feed and the polarization selective surface (PSS) are placed on the concave surface of the main reflecting paraboloid, assuming that the feed operates in the C-band and X-band. The incoming wave can pass through the PSS operating in C-band for TE mode while in X-band for TM mode. That is, PSS transmission surface can select and transmit TE polarized electromagnetic signals and TM polarized electromagnetic signals excited by the feed. Through PSS, single-mode polarized waves of different wave bands can be generated, which greatly enhances the use function of communication satellites.

In [15], it proposes a kind of PSS with polarization separation function. When the capacitive surface and the inductive surface with complementary structures have lateral displacement along the periodic arrangement direction, the PSS becomes a polarization separation structure with TM bandpass and TE bandstop. In [16], based on electromagnetic resonance theory, a novel PSS is designed by loading lumped LC devices into periodic arrays. The designed structure has good polarization separation characteristics near the specific frequency. In the range of 0° - 40° , the structural transmission characteristics of TE and TM polarization are stable. Based on the design theory of metamaterial structures, [17] proposes two layers of PSS and one-sided PSS, both of which can simultaneously realize the first-order selective transmission of TE and TM waves in a specific frequency band.

However, the above designs based on traditional FSS also need to be improved. Firstly, the size and thickness of traditional FSS to achieve the required transmission characteristics is too large, which makes it very difficult to apply it to satellites with limited space. Secondly, the angle stability of the above designs are good in the range of 0° - 40° , but in practical application, it is important to keep a wider

angle range. Thirdly, the above designs as a first-order filter response, its bandpass response is not flat enough, its bandwidth is narrow, and it cannot provide a good level of out-of-band suppression, so it is not enough to meet the needs of satellite communication.

In order to solve these problems, it is necessary to design PSS with high order bandpass and large angle stable response. Conventionally, higher-order bandpass FSS is designed by cascading a plurality of first-order FSS panels with a dielectric substrate loaded with a quarter of the working wavelength. Thus, a flat bandpass response is obtained, and cascading multiple bandpass FSS panels can expand bandwidth and ensure stable transmission characteristics. However, this kind of multi-panel structure is thick and heavy, which is not suitable for practical engineering design. In order to reduce the longitudinal dimension (i.e. total thickness and profile) of the multi-panel structure, some scholars at home and abroad have successively studied and proposed to design a bandpass FSS based on the coupling resonance filtering mechanism: R. Pous and D. M. Pozar first proposed a method based on "patch - aperture - patch" coupling to design FSS with low profile and higher-order transmission response [18]. In [19]–[22], FSS based on the structure of substrate integrated waveguide cavity is proposed, which is used to achieve low profile and higher order transmission response. K. Sarabandi and N. Behdad studied the transmission response of FSS based on sub-wavelength structure (or metamaterial) and realized the resonance of long wavelength controlled by small size structure through the coupling between sub-wavelength units [23]–[32].

Therefore, the bandpass FSS panels based on the coupling resonance filtering mechanism have stable and excellent transmission performance through cascade coupling of thin-layer media, can realize low profile and higher-order wide-band filtering characteristics, and can also suppress grating lobes and maintain large angle stability. The coupled FSS does not need to maintain a panel spacing of $0.2\lambda' - 0.3\lambda'$ like the traditional multi-panel FSS structure, λ' represents the center frequency wavelength of the operating frequency band, thus maintaining a good low profile characteristic.

In this paper, according to the coupling resonance filtering mechanism, a novel three layer PSS capable of providing stable second-order multi-band response is designed by adding a metal square aperture structure between two identical asymmetric Jerusalem cross patches. The simulation results show that the structure has a miniaturization, good second-order polarization selection, and high out-of-band suppression level response. In addition, it has excellent angular stability in the range of $0^\circ - 60^\circ$ of incidence. By adjusting the parameter sizes of the asymmetrical Jerusalem cross patch and the metal square aperture, the passband can be independently adjusted within a certain range according to the actual application requirements. Finally, rotating the structure of the proposed PSS by 90° can switch the overall polarization selection state, which provides a new design idea for the design of polarization wave generator and polarization separation structure.

Using printed circuit board technology, the prototype was fabricated and measured. The measure results are in good agreement with the simulated ones.

II. DESIGN OF POLARIZATION SELECTIVE SURFACE

Based on the coupling resonance filtering mechanism, FSS is synthesized from a second-order band-pass microwave filter topology. FSS is a multilayer structure composed of a periodic structure with effective inductance, capacitance and resonant surface impedance and two thin dielectric substrates. In the following design process, a FSS design is given and discussed.

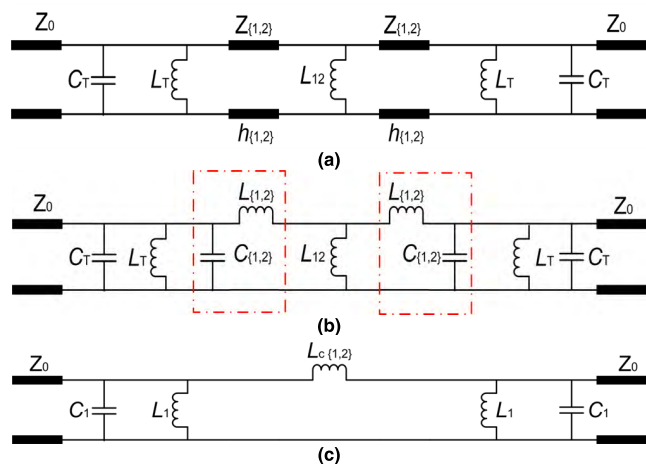


FIGURE 2. (a) The equivalent circuit model of the second-order bandpass filter used in this paper. (b) The simplified LC equivalent network is used to represent the equivalent circuit of the transmission line. (c) Typical circuit model of second-order coupled resonant filter after $T-\pi$ transformation.

Fig.2(a) shows the topology of a second-order bandpass filter, which is the basis of the proposed second-order bandpass FSS. The filter is composed of two resonators separated from inductor L_{12} by two short transmission lines, each resonator is composed of parallel LC circuits (L_T and C_T). The short transmission line has a characteristic impedance of $Z_{\{1,2\}}$ and a total length of $h_{\{1,2\}}$. The free space on both sides of the filter is modeled as a semi-infinite transmission line with characteristic impedance of $Z_0 = 377\Omega$. Fig.2(b) shows a simplified equivalent circuit model using the simple LC equivalent networks ($L_{\{1,2\}}$ and $C_{\{1,2\}}$) shown in the red box instead of the filter transmission line in Fig.2(a). The circuit model shown in Fig. 2(c) is obtained by converting the inductive T network into a π network. In [33], a general method for constructing the N-order coupled resonant bandpass filter model is proposed. From [33] it can be seen that the circuit model shown in Fig.2(c) is a typical topology with a second-order coupled resonant bandpass filter. Therefore, the model shown in Fig.2(a) is sufficient to achieve the second-order bandpass response.

In order to design the target FSS, the values of the components used in the equivalent circuit model of Fig.2, should be optimized, which will produce the required response, using

the approximate synthesis formula provided in this section. These values can then map out the physical and geometric parameters of the structure. Referring to [33], we assume that the center frequency is f_0 , the relative bandwidth $\delta = BW/f_0$, the working bandwidth BW , and the normalized quality factor Q are all known. Using these parameters, the values of the components can be obtained, as follows:

$$C_1 = \frac{q}{\omega_0 Z_0 \delta} \quad (2.1)$$

$$L_1 = \frac{1}{\omega^2 (C_1 - K_{1,2} \cdot \delta \cdot C_1)} \quad (2.2)$$

$$L_{c\{1,2\}} = \frac{1}{\omega_0^2 \cdot K_{1,2} \cdot \delta \cdot C_1} \quad (2.3)$$

$$L_{12} = \frac{2L_1^2}{3L_1 + L_{c\{1,2\}}} \quad (2.4)$$

$$L_{\{1,2\}} = \frac{L_1 \cdot L_{c\{1,2\}}}{3L_1 + L_{c\{1,2\}}} \quad (2.5)$$

$$C_{\{1,2\}} = \frac{\epsilon_0 \cdot \epsilon_r\{1,2\} \cdot h_{\{1,2\}}}{2} \quad (2.6)$$

$$Z_{\{1,2\}} = \frac{Z_0}{\sqrt{\epsilon_r\{1,2\}}} \quad (2.7)$$

$$h_{\{1,2\}} = \frac{L_{\{1,2\}}}{\mu_0 \cdot \mu_r\{1,2\}} \quad (2.8)$$

$$C_T = C_1 - \frac{\epsilon_0 \cdot \epsilon_r\{1,2\} \cdot h_{\{1,2\}}}{2} \quad (2.9)$$

where $K_{1,2}$ represents the normalized coupling coefficient between the two resonators in Fig.2(a), $L_{c\{1,2\}}$ represents the coupling inductor of the equivalent circuit model in Fig.2(c), $\epsilon_r\{1,2\}$ and $\mu_r\{1,2\}$ represents the relative dielectric constant and the relative permeability of the dielectric substrate, respectively. Using the above expression, the initial value is given to for optimization, and the value of the components used in the equivalent circuit model can be obtained.

Since FSS is a spatial microwave filter, the second-order coupled resonant bandpass filter topology discussed above can be used to synthesize the second-order bandpass FSS. The filter shown in Fig.2 can be considered as an equivalent circuit model of the second-order bandpass FSS of the normal incident plane electromagnetic wave. The required FSS structure itself can be directly synthesized from the equivalent circuit shown in Fig.2(a). The structure consists of three metal layers separated from each other by two thin dielectric substrates. By mapping component parameter values to physical parameters, the two transmission lines of Fig.2(a) are implemented using two F4B-2 thin dielectric substrates with a thickness of $h = 1$ mm, a dielectric constant of $\epsilon_r = 2.65$, and a loss tangent of 0.001. To generate second-order polarization selection response, the top and bottom metal layers are composed of a periodic array of asymmetric Jerusalem crosses for realizing parallel LC circuits (L_T and C_T). The copper clad thickness on the dielectric substrate was 0.017 mm, where $X = 3.25$ mm, $Y = 6.25$ mm, $L_1 = 0.5$ mm, $L_2 = 5.5$ mm, $L_3 = 2.5$ mm, $L_4 = 0.5$ mm, $P = 3$ mm, $Q = 0.25$ mm, as shown in Fig.3(a). In the figure, the yellow part represents the metal

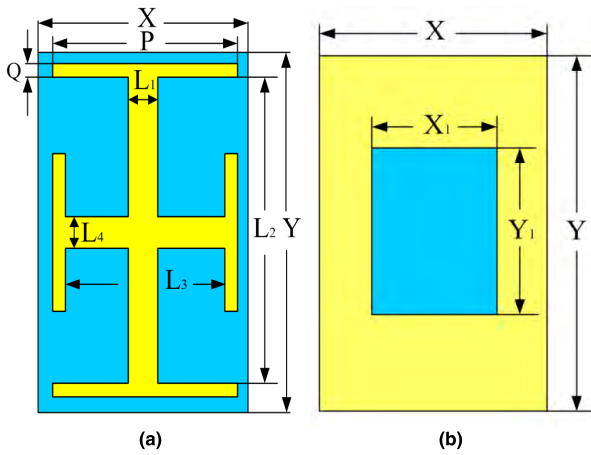


FIGURE 3. Schematic diagram of each layer structure of the synthesized PSS. (a) Top and bottom metal layer structures. (b) Intermediate metal layer structures.

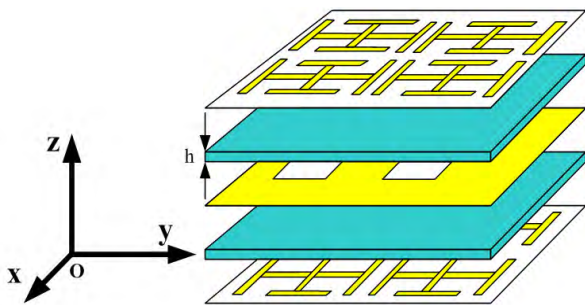


FIGURE 4. Three-dimensional topology of synthesized PSS.

and the blue part represents the dielectric substrate. Since the side length of these capacitive patches is much shorter than half a wavelength, these structures are non-resonant, and their periodic arrangement only presents a capacitive impedance to incident waves. The intermediate metal layer is composed of a metal square aperture for realizing the inductor $L_{(1,2)}$ in Fig.2(a), as shown in Fig.3(b), where $X_1 = 2.25\text{mm}$ and $Y_1 = 2.75\text{mm}$. This metal layer presents the inductive impedance to the incident waves. Fig.4 shows a synthesized three-dimensional topology of the proposed PSS.

For the novel PSS structure shown in Fig.4, when TE and TM waves are normally incident along the +Z direction, simulation is carried out using CST microwave studio electromagnetic simulation software. The S-parameter curves are shown in Fig.5, in which S_{21} represents the transmission curve and S_{11} represents the reflection curve. As can be seen from Fig.5, the proposed PSS structure realizes the separation of the polarization waves of the two modes when TE and TM waves are incident. The selective transmission of polarized waves in two modes is realized simultaneously in specific band, and a good second-order response is further achieved. Among them, the resonance frequency of TE passband is $f_1 = 7.36\text{GHz}$ and $f_3 = 26.75\text{GHz}$, respectively, and the resonance frequency of TM passband is $f_2 = 11.45\text{GHz}$.

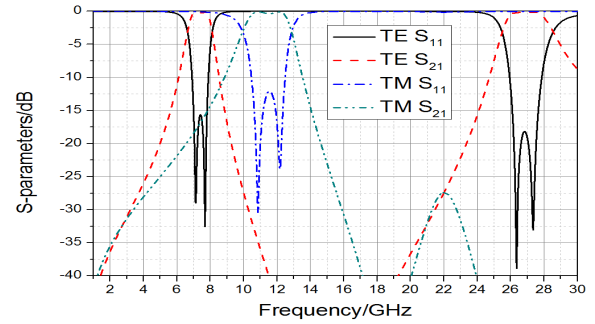


FIGURE 5. S-parameters curves of PSS at normal incidence of TE and TM waves.

In order to understand the principle of polarization selection and resonance, the induced current distribution of PSS at two resonance frequencies $f_1 = 7.36\text{GHz}$ and $f_2 = 11.45\text{GHz}$ are given in Fig.6 and Fig.7, respectively. The arrow indicates the direction of the current, while the color indicates the relative magnitude. The darker the color is, the greater the current intensity is.

Fig.6(a) and Fig.6(b) show the current distribution on the asymmetric Jerusalem cross structure and the intermediate metal layer, respectively, when TE waves are normally incident and at $f_1 = 7.36\text{GHz}$. Figs.6(c) and 6(d) show the current distribution of asymmetric Jerusalem cross structure and intermediate metal layer, respectively, when TM wave is normally incident and at $f_1 = 7.36\text{GHz}$. As can be seen from Fig.6(a) and Fig.6(b), asymmetric Jerusalem cross and intermediate metal layer have a strong current distribution in the y- direction. As can be seen from Fig.6(c) and Fig.6(d), the current distribution on the asymmetric Jerusalem cross and the intermediate metal layer is very weak, and it can be neglected in both the x- and y- directions. In addition, it can be seen that the excitation of the current in the y-direction causes the polarization wave of TE mode to be transmitted. Furthermore, since the current flows in the y-direction in Fig.6(a) and Fig.6(b) are opposite, it is obvious that a first-order resonance occurs between the asymmetric Jerusalem cross and the intermediate metal layer. Moreover, there is a strong electromagnetic coupling between the top and bottom metal layers and the intermediate metal layer, so the transmission pole point of PSS is caused by coupling resonance. When $f_3 = 26.75\text{GHz}$, the transmission principle of TE mode polarized wave is the same as $f_1 = 7.36\text{GHz}$.

Similarly, Fig.7(a) and Fig.7(b) show the current distribution on the asymmetric Jerusalem cross structure and the intermediate metal layer when TE wave is normally incident at $f_2 = 11.45\text{GHz}$. Fig.7(c) and Fig.7(d) show the current distribution of asymmetric Jerusalem cross structure and intermediate metal layer when TM wave is normally incident at $f_2 = 11.45\text{GHz}$. As can be seen from Fig.7(a) and Fig.7(b), the current distribution on the asymmetric Jerusalem cross and the intermediate metal layer is very weak and negligible in both the x- and y- directions. From Fig.7(c) and Fig.7(d), asymmetric Jerusalem cross and intermediate metal layer

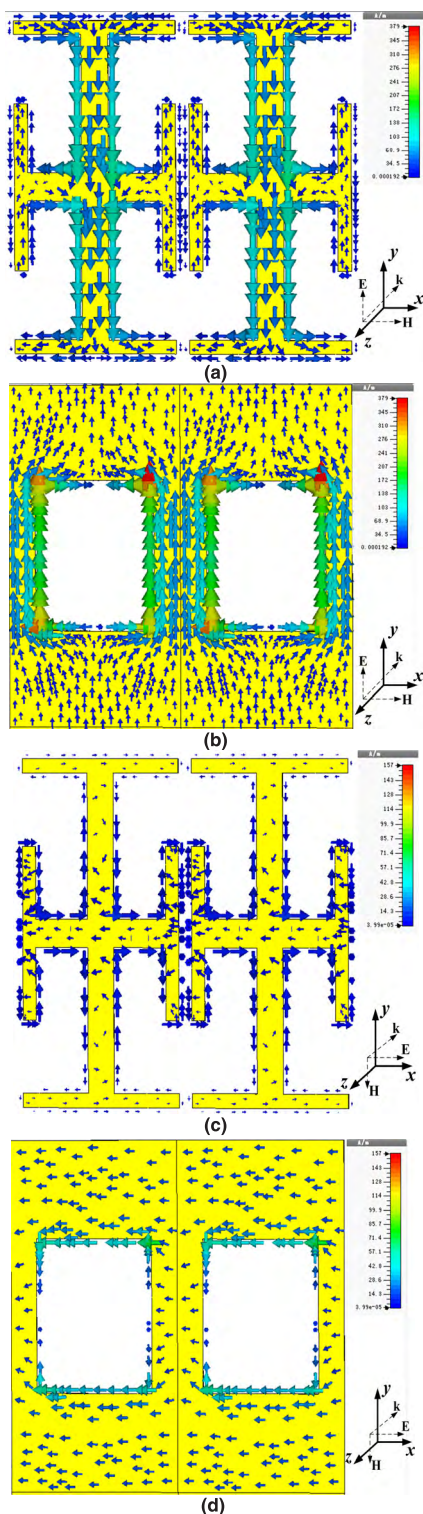


FIGURE 6. When $f_1 = 7.36$ GHz, the current distribution of the top and bottom metal layers and the middle metal layer under the normal incidence of TE and TM waves. (a) TE mode, the current distribution of the top and bottom metal layers. (b) TE mode, the current distribution of the intermediate metal layer. (c) TM mode, the current distribution of the top and bottom metal layers. (d) TM mode, the current distribution of the intermediate metal layer.

have a strong current distribution in the x-direction. Thus, it is concluded that the excitation of the current in the x-direction causes the TM polarization wave to be transmitted.

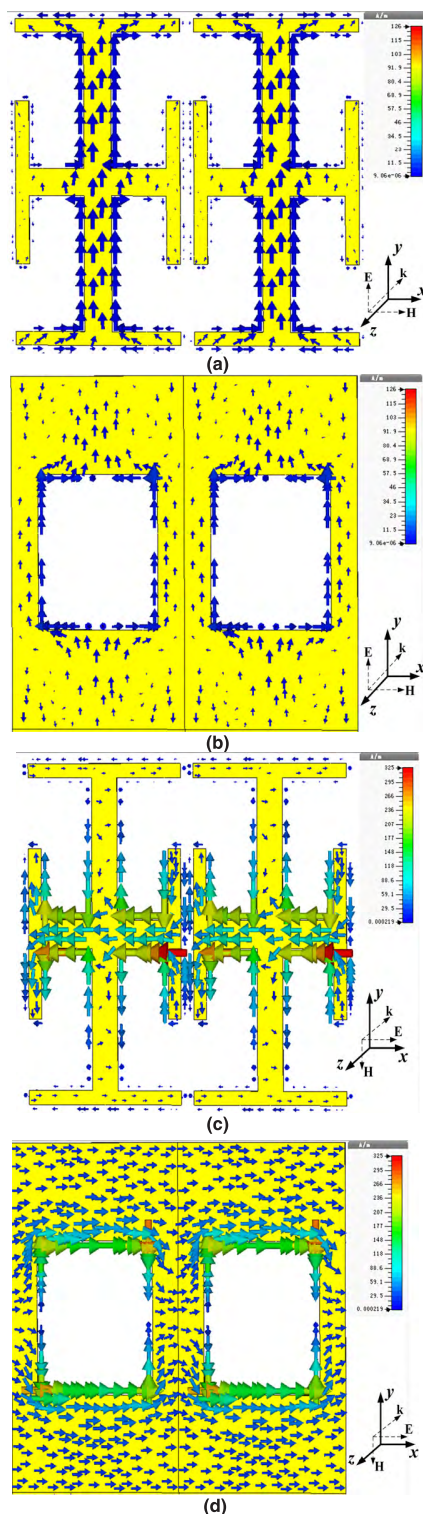


FIGURE 7. When $f_2 = 11.45$ GHz, the current distribution of the top and bottom metal layers and the middle metal layer under the normal incidence of TE and TM waves. (a) TE mode, the current distribution of the top and bottom metal layers. (b) TE mode, the current distribution of the intermediate metal layer. (c) TM mode, the current distribution of the top and bottom metal layers. (d) TM mode, the current distribution of the intermediate metal layer.

Furthermore, since the current flows in the x-direction in Fig.7(c) and Fig.7(d) are opposite, it is obvious that a first-order resonance occurs between the asymmetric Jerusalem

cross and the intermediate metal layer. Moreover, there is a strong electromagnetic coupling between the top and bottom metal layers and the intermediate metal layer, so the transmission pole point of PSS is caused by coupling resonance.

From the above analysis, it is concluded that the long and the short arms of the asymmetric Jerusalem Cross play a key role in the transmission selection of TE and TM waves, respectively. Therefore, using structural asymmetry to transmit polarized waves provides a new design idea for the designing of polarization wave generator and polarization separation structure.

III. ANALYSIS OF FACTORS INFLUENCING PSS TRANSMISSION CHARACTERISTICS

From S-parameters curve shown in Fig.5, it is observed that the insertion loss of the three passbands is less than 0.5dB. The -3dB transmission bandwidths are 1.57GHz (6.50GHz-8.07GHz) and 3.04 GHz (25.42GHz-28.46GHz) for TE wave under normal incidence while the -3dB transmission bandwidth is 2.98GHz (9.90GHz-12.88GHz)for TM wave. The relative bandwidths are 21.33 %, 11.36 % and 26.03%, respectively. The first pass band of PSS is presented with free space wavelength of $\lambda_1 = 40.76\text{mm}$, thus its element size is in the range of $0.08\lambda_1-0.15\lambda_1$, the miniaturization characteristic of PSS is remarkable. For each passband, its falling edge is steeper, and the amplitude of the transmission coefficient will change by not less than 8dB for every 1GHz, indicating that the three transmission windows have high frequency selectivity and out-of-band suppression level. In the first frequency band of 6.50GHz-8.07GHz, the lowest reflectivity of TE wave can reach -40dB, and the transmission rate of TM wave is less than -12dB. In the frequency range of 25.42GHz-28.46GHz, the reflectivity of TE wave can reach -39dB at the lowest, and TM wave has no transmission in this passband. In the frequency range of 9.94GHz-12.88GHz, the lowest reflectivity of TM wave can reach -40dB, and the transmission rate of TE wave is less than -12dB. Therefore, this miniaturized PSS achieves good bandpass polarization selection characteristics for TE and TM waves in a specific frequency band.

A. INFLUENCE OF INCIDENCE ANGLE ON TRANSMISSION

In the subsection, the angle stability of the proposed PSS structure to polarized waves in different modes is analyzed by simulating the incident of TE and TM waves with different incident angles θ from 0° to 60° . Other parameters of PSS are unchanged. Incidence angle θ is defined as the angle between the +Z direction and the wave vector k . The transmission and reflection curves for TE and TM wave incidence are shown in Fig.8.

It can be seen from Fig.8(a) and Fig.8(b), the passband does not shift when TE wave is incident in the range of $0^\circ-60^\circ$ angle of incidence, and the position of the center frequency in the passband is basically unchanged. And with the increase of incident angle, -3dB bandwidth decreases slightly and out-of-band suppression capability increases slightly. Because for

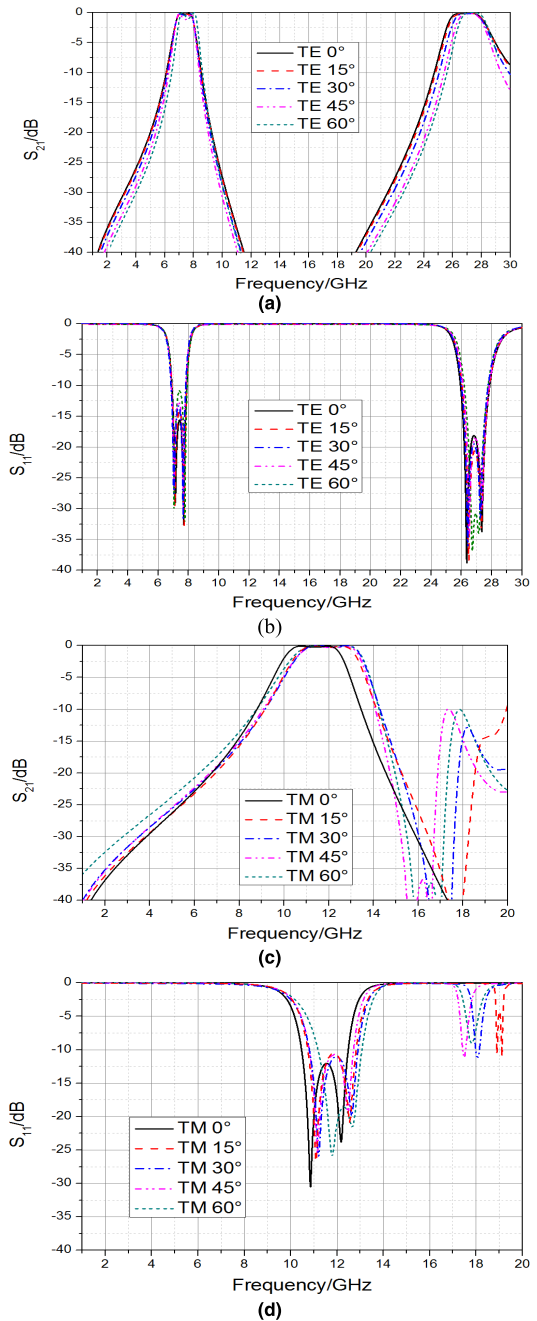


FIGURE 8. The transmission and reflection curves of TE and TM waves incidence at different angles.

TE waves, there are [34]–[37]:

$$Z_{TE} = Z / \cos \theta, \quad Q = Z_{TE} \cdot \sqrt{C/L} \quad (3.1)$$

In the formula (3.1), θ is the incidence angle, and C, L are equivalent capacitance and equivalent inductance of PSS structure respectively, and Z is equivalent impedance of PSS structure when electromagnetic wave is incident normally. When TE wave is incident, the equivalent impedance Z_{TE} increases with the increase of incident angle θ , and the Q value also increases with the increase of Z_{TE} . Since the Q

value is inversely proportional to the TE passband bandwidth, the TE passband bandwidth of the proposed PSS structure is reduced.

From Fig.8(c) and Fig.8(d), it can be seen that, in the range of $0^\circ - 60^\circ$ angle of incidence, the passband moves slightly to high frequency when TM wave is incident. However, when the incident angle is increased from 15° to 60° , grating lobes appear at high frequencies. Because they are far away from the working frequency point and their transmission rates are less than -10dB , they will not interfere with the polarization selective filtering characteristics of PSS. As the incident angle increases, the bandwidth slightly increases, and the out-of-band suppression capability decreases. Because for TM waves, there are [34]–[37]:

$$Z_{TM} = Z \cdot \cos \theta, \quad Q = Z_{TM} \cdot \sqrt{C/L} \quad (3.2)$$

In the formula (3.2), when TM wave is incident, the equivalent impedance Z_{TM} decreases with the increase of incident angle θ , and the Q value decreases with the decrease of Z_{TM} . Since the Q value is inversely proportional to the TM passband bandwidth, the TM passband bandwidth of the proposed PSS structure increases. Simulation results show that the proposed PSS has good angle stability and polarization selection characteristics for polarized waves incident in a wide range of $0^\circ - 60^\circ$.

Under oblique incidence conditions, with the increase of incident angle, the change of projection area of PSS basic unit in the direction perpendicular to the incident direction will obviously decrease. Therefore, the projection effect will cause the equivalent capacitance C and equivalent inductance L of PSS structure to change to a certain extent, but their ratio (C/L) will hardly change [38]. Therefore, when analyzing the influence of incident angle on Q in formula (3) (4), only the relationship between incident angle and PSS equivalent impedance (Z_{TE}, Z_{TM}) is analyzed.

B. INFLUENCE OF COUPLING DIELECTRICS ON TRANSMISSION CHARACTERISTIC

First, for the PSS proposed in Fig.4, the relative dielectric constant of the fixed coupling dielectric is 2.65, changing only the thickness of the two layers of dielectric. Set h to 0.9mm, 1mm and 1.1mm respectively, other structural parameters remain unchanged. The influence of dielectric thickness on PSS transmission characteristics was studied, the simulation results are shown in Fig.9. Secondly, the fixed coupling dielectric thickness h is 1 mm, the relative dielectric constants are set to 2.2, 2.65, and 3.2 respectively, other structural parameters remain unchanged. The influence of relative dielectric constant ϵ_r on PSS transmission characteristics is studied. the simulation results are shown in Fig.10.

As can be seen from Fig.9, with the increase of the dielectric thickness h , the coupling effect between the layers will be weakened. First, the most prominent feature is that with the increase of h , the in-band insertion loss at the peak frequency point decreases. Secondly, with the increase of h , each passband becomes more flat. Finally, from Fig.9(a), for TE

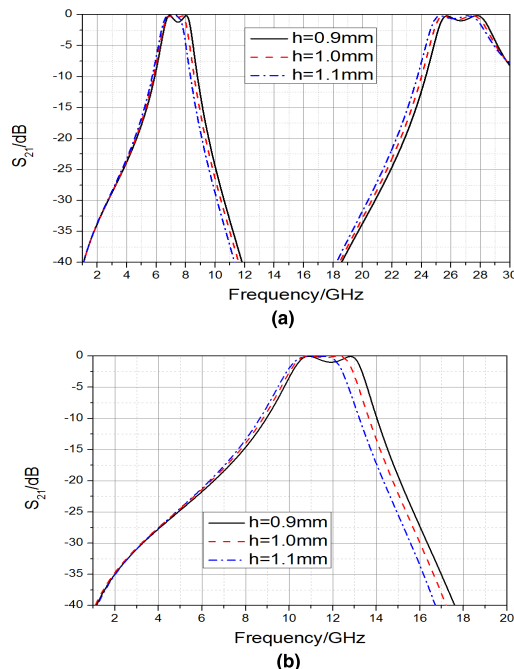


FIGURE 9. Transmission curve of PSS at different dielectric thicknesses when normal incidence.

wave incidence, the TE low-frequency passband bandwidth decreases with the increase of h , and the TE high-frequency passband bandwidth increases with the increase of h . From Fig.9(b), for TM wave incidence, the TM passband bandwidth decreases with the increase of h . And the resonant frequencies of the three passbands all slightly shift to low frequencies with the increase of h .

According to Munk’s design theory, the resonant frequency $f = f_0/\sqrt{(1 + \epsilon_r)/2}$ in the medium, where f_0 is the resonant frequency in vacuum. From Figs.10(a) and 10(b), it can be seen that the other parameters of PSS are kept unchanged whether the incident TE wave or TM wave, and when the relative dielectric constant ϵ_r increases from 2.2 to 3.2, the resonant frequency moves to the low frequency, fully conforming to munk’s theory. Considering the transmission of low frequency band signals, it can be processed on a dielectric substrate with a relatively high dielectric constant and a relatively thin thickness, which can be directly pasted like wallpaper and is convenient for application.

C. INFLUENCE OF SIZE CHANGE OF ASYMMETRIC JERUSALEM CROSS AND INTERMEDIATE METAL LAYER ON PSS TRANSMISSION CHARACTERISTIC

From the above analysis, it is concluded that the long and short arms of the asymmetric Jerusalem Cross play a key role in the selective transmission of TE and TM waves. Therefore, the change of the size of the long arm and the short arm of the asymmetric Jerusalem cross, as well as the change of the size of the intermediate metal layer, will change the positions of the transmission pole points and the passband, thus changing the corresponding transmission characteristic.

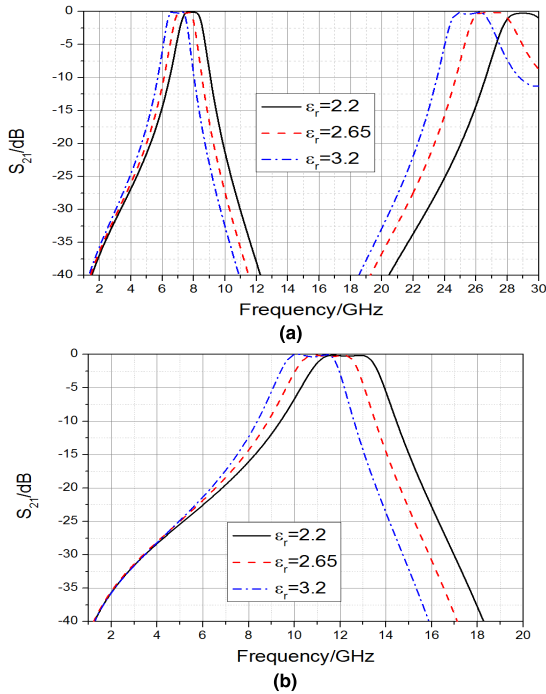


FIGURE 10. Influence of PSS transmission characteristics under different relative dielectric constants at normal incidence.

According to the simulation of the model shown in Fig.4, we change the sizes L_1 and L_2 of asymmetric Jerusalem cross long arms, and the influence of L_1 and L_2 of different sizes on PSS transmission performance when electromagnetic waves are incident normally is shown in Fig.11. As can be seen from Fig.11(a), with the increase of L_1 , the falling edge on the right side of TE low frequency passband moves toward the direction of high frequency, and the bandwidth increases. The falling edge on the left side of the TE high-frequency passband also moves toward the high-frequency direction, reducing the bandwidth. The center frequencies of both passbands are slightly shifted to high frequencies as L_1 increases. As can be seen from Fig.11(c), with the increase of L_2 , the two passbands of TE polarization move toward the low frequency direction as a whole, and the bandwidth hardly changes, so the value of L_2 only determines the position of TE passband. As can be seen from Fig.11(b) and Fig.11(d), the width and position of the TM passband are almost unchanged no matter how L_1 and L_2 change. This further shows that the asymmetric Jerusalem cross long arm plays a key role in the selective transmission of TE polarized waves.

Similarly, according to the simulation of the model shown in Fig.4, we change the sizes L_3 and L_4 of asymmetric Jerusalem cross short arms, and the influence of L_3 and L_4 of different sizes on PSS transmission performance when electromagnetic waves are incident normally is shown in Fig.12. As can be seen from Fig.12(b), with the increase of L_3 , the TM passband moves toward the low frequency direction as a whole, and the bandwidth hardly changes. Therefore, the value of L_3 only determines the position of

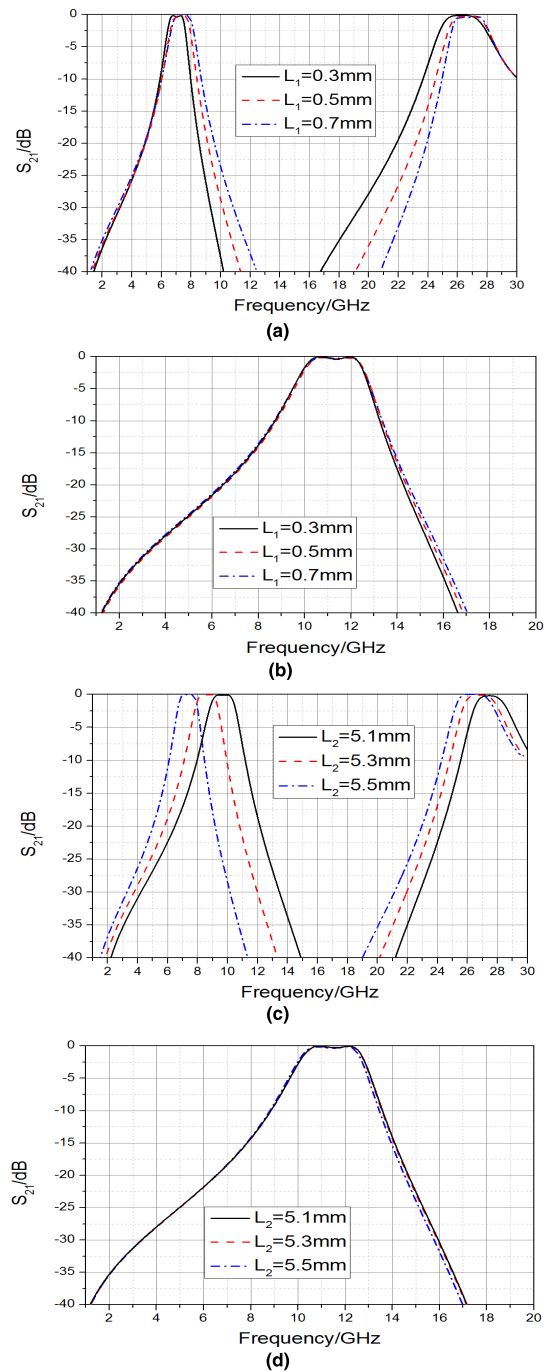


FIGURE 11. Influence of L_1 and L_2 of different sizes on PSS transmission performance when electromagnetic waves are incident normally.

the TM passband. As can be seen from Fig.12(d), with the increase of L_4 , the falling edge on the right side of TM passband moves toward the high frequency direction, the bandwidth increases, and the center frequency slightly moves toward the high frequency. As can be seen from Fig.12(a) and Fig.12(c), the width and position of the TE passband are almost unchanged no matter how L_3 and L_4 change. This further shows that the asymmetric Jerusalem cross short arm

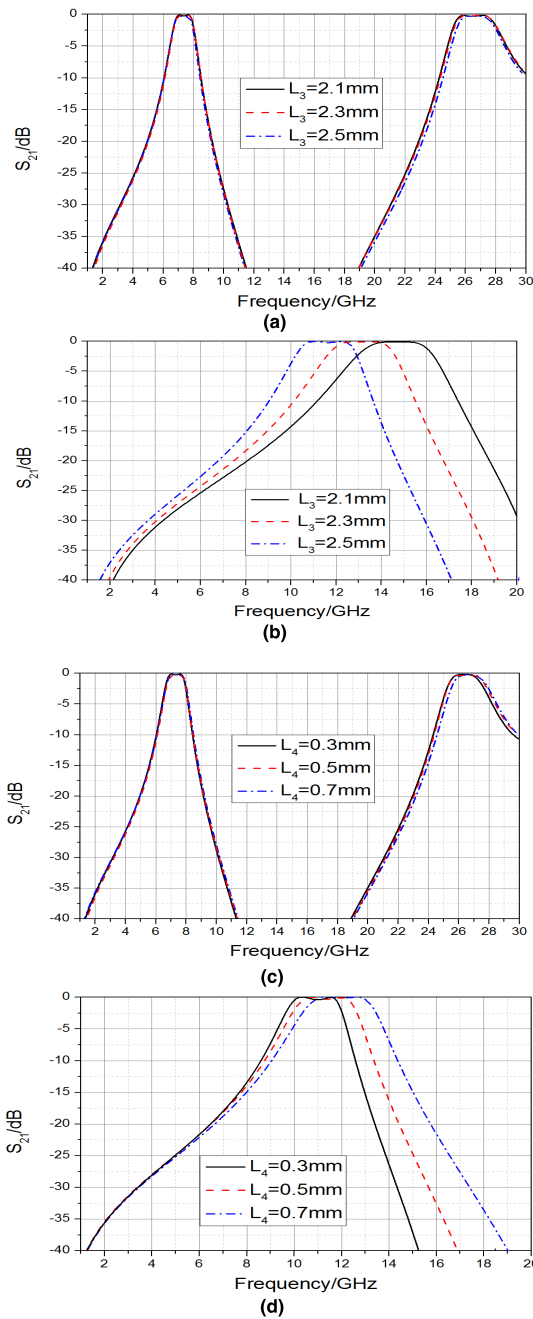


FIGURE 12. Influence of L_3 and L_4 of different sizes on PSS transmission performance when electromagnetic waves are incident normally.

plays a key role in the selective transmission of TM polarized waves.

According to the simulation of the model shown in Fig.4, we change that aperture size X_1 and Y_1 of the intermediate metal layer, and the influence of X_1 and Y_1 of different sizes on PSS transmission performance when electromagnetic waves are incident normally is shown in Fig.13. As can be seen from Figs.13(a) and 13(b), with the increase of X_1 , the left falling edge of TE passband moves toward the low frequency direction, and the passband bandwidth increases.

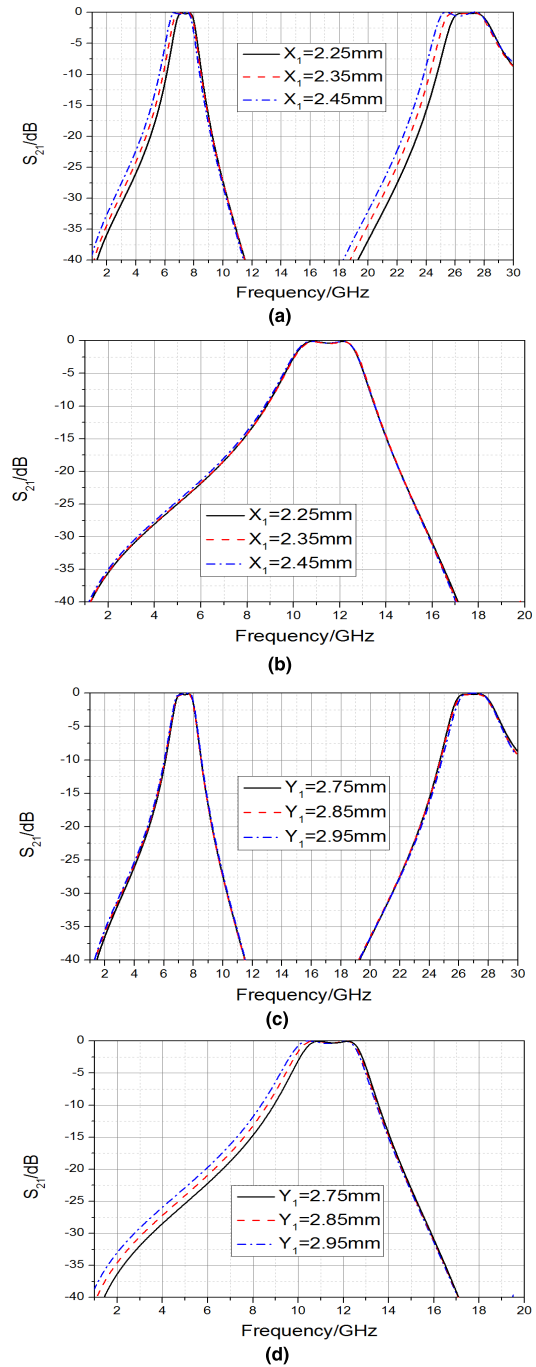


FIGURE 13. Influence of X_1 and Y_1 of different sizes on PSS transmission performance when electromagnetic waves are incident normally.

No matter how X_1 changes, the TM passband width and position are almost unchanged. Similarly, as can be seen from Figs.13(c) and 13(d), with the increase of Y_1 , the left falling edge of TM passband moves toward the low frequency direction, and the passband bandwidth increases. No matter how Y_1 changes, the TE passband width and position are almost unchanged.

From the above analysis, it can be seen that the transmission characteristics of TE or TM passband can be

independently controlled by the size change of a certain parameter in the asymmetric Jerusalem cross structure and the intermediate metal layer. Therefore, based on the independent controllability of parameters, TE passband and TM passband can be independently adjusted within a certain range according to actual application requirements.

D. INFLUENCE OF THE PROPOSED PSS’S OVERALL ROTATION OF 90° ON ITS TRANSMISSION CHARACTERISTIC

When TE and TM waves are incident normally, if PSS structure is rotated 90°, its polarization selection state can be switched. The CST microwave studio electromagnetic simulation software was used for simulation calculation, and the results are shown in Fig.14. Among them, Fig.14(a) shows a comparison curve of the transmission characteristics of TE waves before and after rotation, and Fig.14(b) shows a comparison curve of the transmission characteristics of TM waves before and after rotation. As can be seen from Fig.14, the original TE bandpass is converted into a TM bandpass and the original TE bandstop is converted into a TM bandstop, that is, the proposed PSS has good reconfigurable characteristics. Similarly, after the PSS structure is rotated 90°, the electromagnetic wave still has good angle stability and polarization selection characteristics in the incident range of 0° -60°. Therefore, the reconfigurable characteristic of PSS provides a new design idea for the design of polarization wave generator and polarization separation structure.

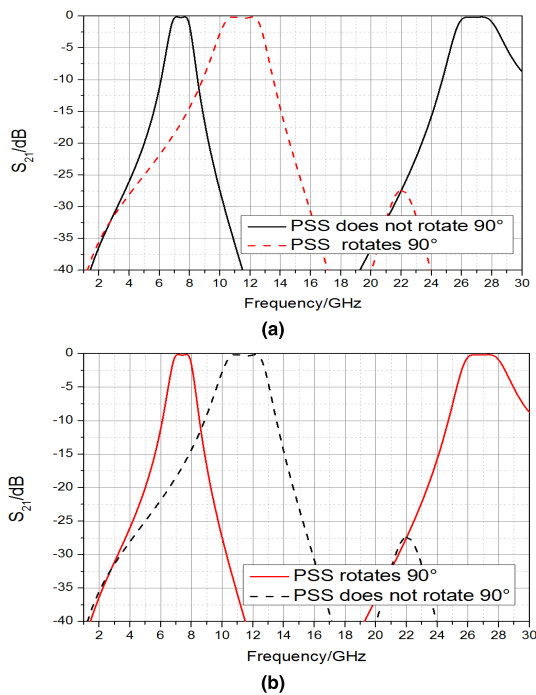


FIGURE 14. Comparison curves of transmission characteristics of polarized waves in different modes before and after rotation. (a) TE mode. (b) TM mode.

IV. EXPERIMENTAL RESULTS

In order to verify the performance of the proposed second-order multi-band PSS, a sample was fabricated using printed circuit board (PCB) technology, as shown in Fig.15. Fig.15(a) shows the asymmetric Jerusalem cross structure of the top and bottom layers of the processed sample. Fig.15(b) shows the square ring aperture structure of the intermediate metal layer of the processed sample. The dielectric substrate parameters of the machined sample are the same as the simulation parameters. The top metal structure was etched on one surface of one dielectric substrate, and the middle and bottom structures were patterned on both sides of the other dielectric substrate. Then the two substrates are glued together. The processed sample plate has an overall structure size of $497.25 \times 500 \text{mm}^2$ and contains 153×80 elements. The performance of the sample was measured by free-space test method. In a microwave anechoic chamber, two double-ridge horn antennas were connected to the receiving and transmitting terminals of the vector network analyzer (VNA), as shown in Fig.16, to be measured by this system. The measuring frequency range is 1-30GHz, and the incidence electromagnetic wave is TE polarized wave and TM polarized wave, and the incidence angles are 0°, 30° and 60° respectively. The distance from the PSS sample to the transmitting antenna is set to 1.4m, and the distance from the PSS sample to the receiving antenna is also set to 1.4m. This arrangement ensures that quasi-plane waves are incident on PSS samples and can effectively receive electromagnetic waves at the receiving end. In order to reduce

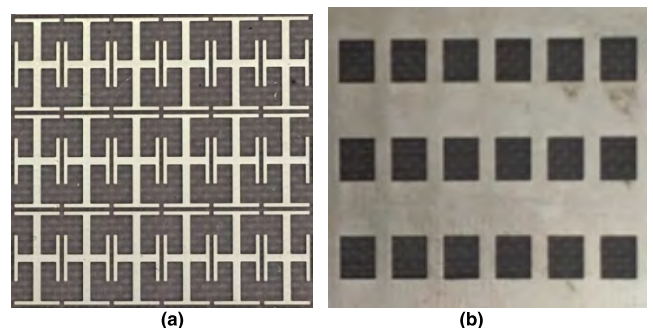


FIGURE 15. Fabricated prototype of the PSS. (a) Top and bottom asymmetric Jerusalem cross structure. (b) Square ring aperture structure of intermediate metal layer.

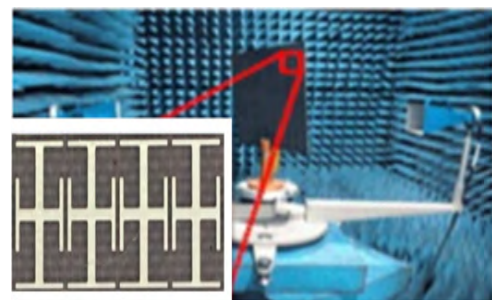


FIGURE 16. The measure system.

the interference of the external environment and the influence of system errors on the measurement, a normalization method is adopted in the measurement process so as to ensure the accuracy of the measurement as much as possible.

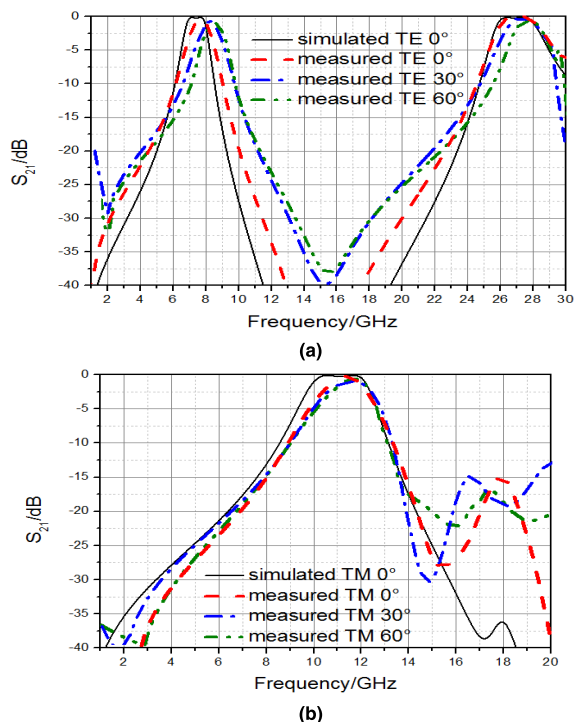


FIGURE 17. Simulation and measurement of TE and TM polarization at different incidence angles transmission curve. (a) TE polarization. (b) TM polarization.

The measured results of PSS samples are shown in Fig.17. Fig.17(a) and Fig.17(b) show the comparison of the measurement results and simulation results of the transmission characteristics of TE and TM polarized waves at different incident angles, respectively. It can be seen from the figure that when TE and TM waves are incident at 0°, 30° and 60° respectively, the measured transmission results are basically consistent with the simulated transmission results, except that the measured curve slightly deviates from the simulated curve. There are three main reasons for the above difference between simulation and measurement:(1) The error between the dielectric constant of the actual sample dielectric substrate and the simulation parameters. (2) Error between actual thickness of sample dielectric substrate and simulation parameters. (3) Artificial or systematic error. The measurement results show that the proposed PSS structure has good polarization selection characteristics and angle stability, which provides a new design idea for designing a polarization wave generator or polarization separation structure on a limited space satellite(or multipath) communication system.

V. CONCLUSION

In this paper, based on the sub-wavelength periodic array structure and the coupling resonance filtering mechanism,

a low profile second-order *multi*-band PSS structure composed of three layers of metal structure and two layers of dielectric substrate is designed in this paper. When TE and TM polarized waves are incident normally, the TE polarized second-order passband is generated in the 6.50GHz-8.07GHz band and 25.42GHz-28.46GHz frequency band, and the TM polarized second-order passband is generated in the 9.90GHz-12.88GHz frequency band. The proposed PSS structure has significant miniaturization characteristics. Simulation and experimental results show that: The proposed PSS structure has good polarization selection characteristics and out-of-band suppression level, and has excellent angular stability in the 0° –60° scanning range. Due to the independent control characteristics of asymmetric Jerusalem cross structure parameters and intermediate metal layer parameters, TE polarized second-order passband and TM polarized second-order passband can be independently adjusted according to actual application requirements within a certain range, making the design more flexible. By rotating the PSS structure by 90°, the polarization filtering state can be switched. That is, the original TE band pass is changed into TM band pass, and the original TE band stop is changed into TM band stop. It provides a new design idea for the design of polarization wave generator and polarization separation structure on a limited space satellite(or multipath) communication system.

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